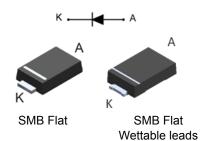
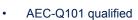


Automotive 1 A - 1200 V ultrafast rectifier



Features





- · Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery times
- · High junction temperature
- ECOPACK2 or ECOPACK3 compliant component on demand

Description

The STTH112-Y, which is using ST's new 1200 V planar technology, is especially suited for switching mode base drive and transistor circuits.

The device is also intended for use as a free-wheeling diode in power supplies and other power switching applications in automotive K functions.



Product status link

STTH112-Y

Product summary				
I _{F(AV)}	1 A			
V_{RRM}	1200 V			
T _j (max.)	175 °C			
V _F (typ.)	1.1 V			
T _{rr} (typ.)	53 ns			



1 Characteristics

Table 1. Absolute ratings (limiting values at T_j = 25 °C, unless otherwise specified)

Symbol	Para	meter	Value	Unit
V _{RRM}	Repetitive peak reverse	Repetitive peak reverse voltage		V
I _{F(AV)}	Average forward current	11 = 135 C 0 = 0.5		А
I _{FSM}	Forward surge current	Forward surge current $t_p = 8.3 \text{ ms}$		Α
T _{stg}	Storage temperature ran	Storage temperature range		°C
T _j ⁽¹⁾	Operating temperature r	Operating temperature range		°C

^{1.} $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-l)}	Junction to lead	20	°C/W

Table 3. Static electrical characteristic

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾ Reverse leakage current		T _j = 25 °C	V _R = V _{RRM}	-		5	
IR ^(*)	I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C	VR - VRRM	-	1	50	μA
V _F ⁽²⁾ Forward voltage drop	T _j = 25 °C	I _E = 1 A	-		1.9		
	Forward voltage drop	T _j = 150 °C	IF - I A	-	1.10	1.55	V

^{1.} Pulsetest: tp = 5 ms, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

 $P = 1.25 \times I_{F(AV)} + 0.330 I_{F^2(RMS)}$

Table 4. Dynamic electrical characteristics

Symbol	Parameter	Test conditions			Тур.	Max.	Unit
t _{rr}	Reverse recovery time	T _j = 25 °C	I _F = 0.5 A; I _{rr} = 0.25 A; I _R = 1 A	-	53	75	no
t _{fr}	Forward recovery time	T _i = 25 °C	I_F = 1 A; $dI_{F/dt}$ = 50 A/µs; V_{FR} = 4.50 V	-		500	ns
V _{FP}	Forward recovery voltage	1		-	20	30	V

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^{2.} Pulsetest: $tp = 380 \mu s$, $\delta < 2\%$



1.1 Electrical characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current

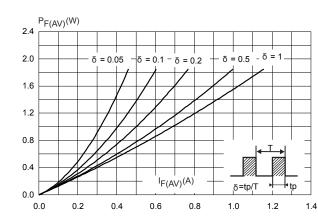


Figure 2. Forward voltage drop versus forward current (typical values)

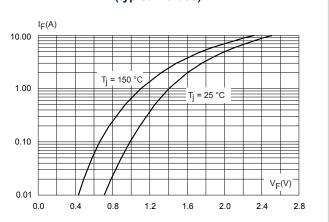


Figure 3. Forward voltage drop versus forward current (maximum values)

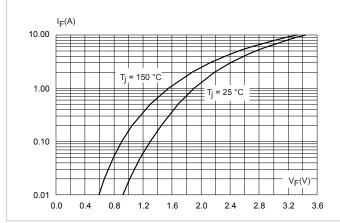


Figure 4. Relative variation of thermal impedance junction to lead versus pulse duration

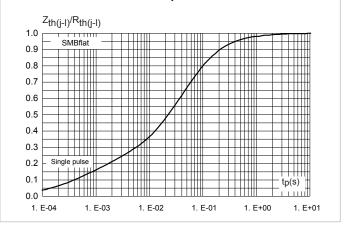


Figure 5. Junction capacitance versus reverse voltage applied (typical values)

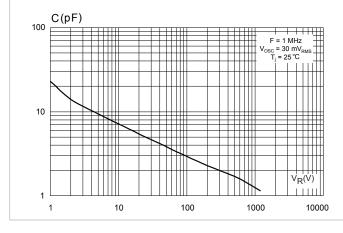
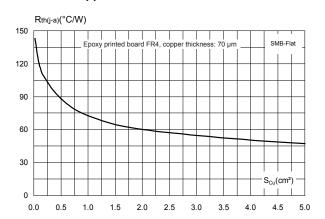


Figure 6. Thermal resistance junction to ambient versus copper surface under each lead



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2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 SMB Flat package information

- Epoxy meets UL94, V0
- Lead-free package

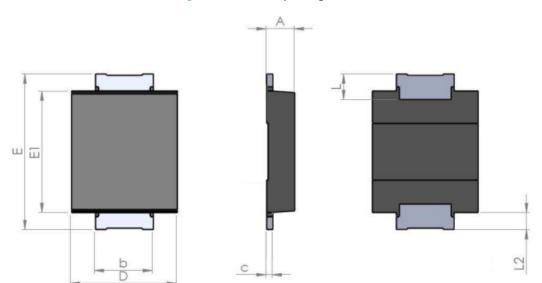


Figure 7. SMB Flat package outline

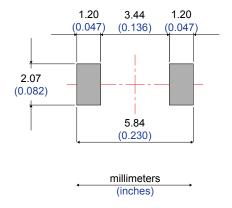
Table 5. SMB Flat mechanical data

			Di	mensions		
Ref.		Millimeters		Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.90		1.10	0.035		0.043
b	1.95		2.20	0.077		0.087
С	0.15		0.40	0.006		0.016
D	3.30		3.95	0.130		0.156
Е	5.10		5.60	0.200		0.220
E1	4.05		4.60	0.159		0.181
L	0.75		1.50	0.030		0.060
L2		0.60			0.024	

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Figure 8. Footprint recommendations, dimensions in mm (inches)



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3 Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH112UFY	F112Y	SMBflat	50 mg	5000	Tape and reel

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Revision history

Table 6. Document revision history

Date	Version	Changes
04-Feb-2014	1	Initial release.
18-Mar-2022	2	Updated Section 2.1 SMB Flat package information.

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